



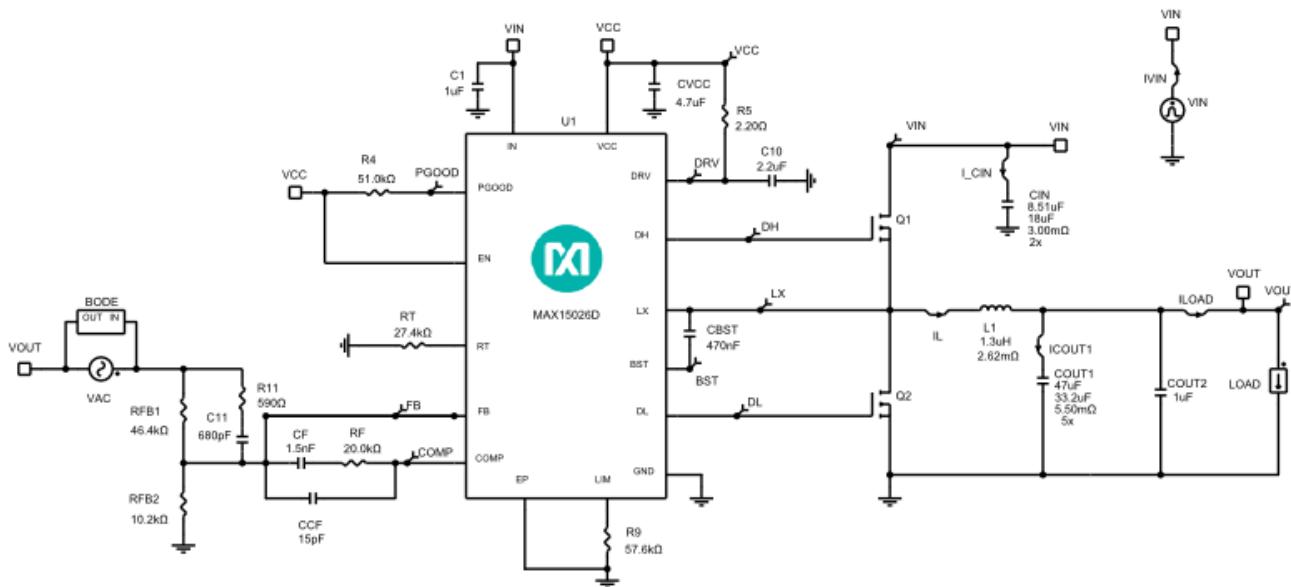
Initial Design

1.0

Design Requirements

Parameter	Value
Minimum Input Voltage	10.8V
Maximum Input Voltage	13.2V
Nominal Input Voltage	12V
Input Voltage Ripple	1%
Output Voltage	3.3V
Output Current	10A
Output Voltage Ripple	1%
Load Step Start Current	5A
Load Step Current	10A
Load Step Edge Rate	5A/us
Output Voltage Load Step Over/Undershoot	3%
Performance Priority	Balance Efficiency and Size
BOM Priority	Cost
Switching Frequency	600kHz
Compensation Type	Type III (Ceramic Output Capacitor)
Ambient Temperature	25°C
Inductor Current Ratio(LIR)	0.3
Break Before Make Time	DH/DL 18ns and DL/DH 20ns
Soft Stop Enable	No
Enable High Power Design	No

Schematic



Thermal Shutdown feature is not modeled in EE-Sim.

This note only applies to online EE-Sim Design Tool : RT and R9 are set to the proper values for the design requirements entered. To change the switching frequency and valley current limit that these components set.

BOM

Ref	Qty	Part Number	Manufacturer	Description
U1	1	MAX15026D	User-Defined	IC
C1	1	CGA4J2X7R1C105K125AA	TDK	Cap Ceramic 1uF 16V X7R 10% Pad SMD 0805 125°C Automotive T/R
C10	1	1206ZC225KAT2A	AVX	Cap Ceramic 2.2uF 10V X7R 10% Pad SMD 1206 125°C T/R
C11	1	04025C681KAT2A	AVX	Cap Ceramic 680pF 50V X7R 10% Pad SMD 0402 125°C T/R
CBST	1	GCM188R71E474KA64D	Murata Manufacturing	Cap Ceramic 0.47uF 25V X7R 10% Pad SMD 0603 125°C Automotive T/R
CCF	1	C0402C150K5GACTU	KEMET Corporation	Cap Ceramic 15pF 50V C0G 10% Pad SMD 0402 125°C T/R
CF	1	CL05B152KB5NNNC	Samsung Electro-Mechanics	Cap Ceramic 0.0015uF 50V X7R 10% Pad SMD 0402 125°C T/R
CIN	2	C1210C186K4PAC	Kemet	Cap Ceramic 18uF 16V X5R 10% SMD 1210 85°C Bulk
COUT1	5	GRM32EC80J476ME64L	Murata	Cap Ceramic 47uF 6.3V X6S 20% SMD 1210 105C Embossed T/R
COUT2	1	LMK212B7105KD-T	Taiyo Yuden	Cap Ceramic 1uF 10V X7R 10% Pad SMD 0805 125°C T/R



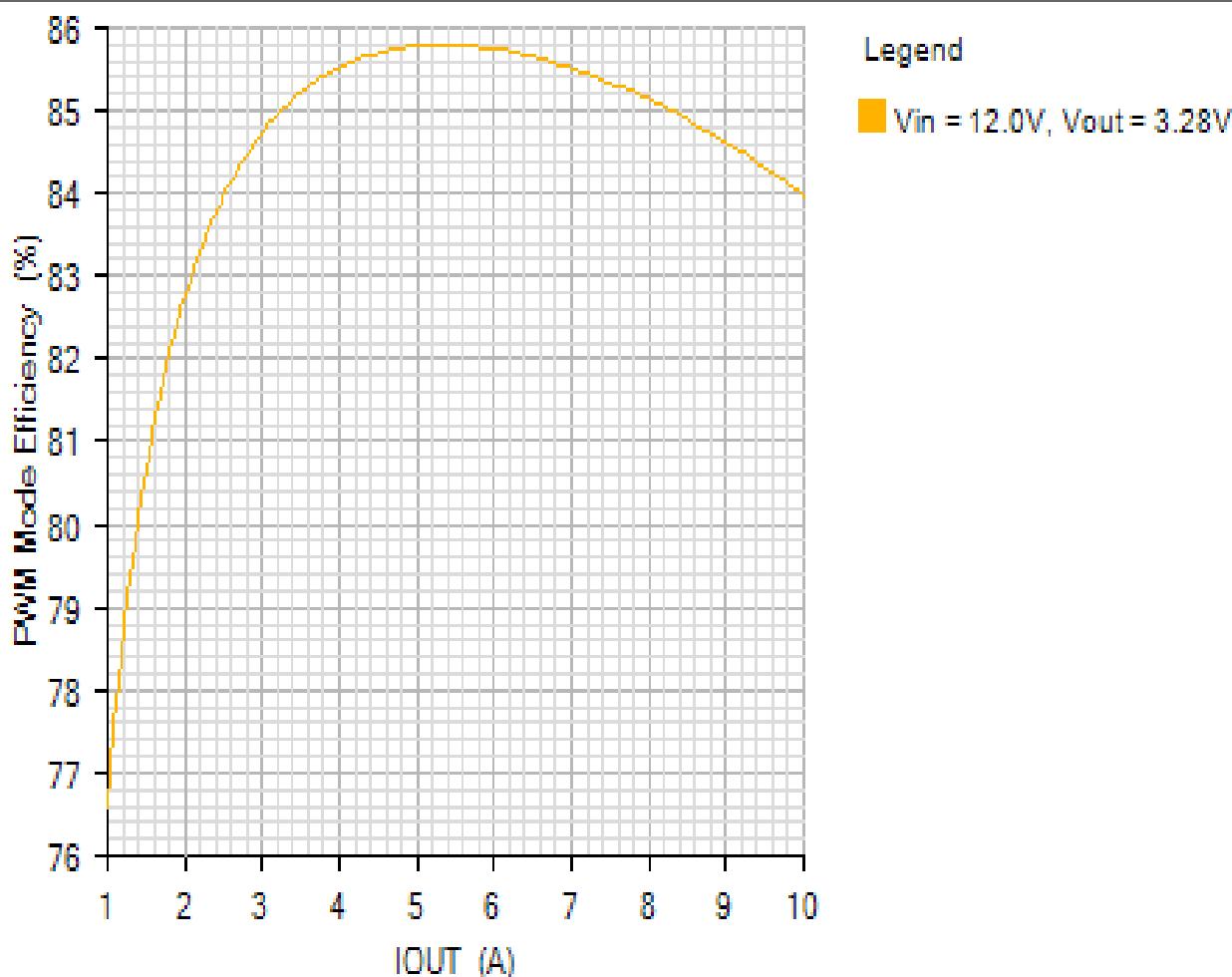
CVCC	1	C2012X7R1A475M125AC	TDK	Cap Ceramic 4.7uF 10V X7R 20% Pad SMD 0805 125°C T/R
L1	1	MLC1250-132MLB	Coilcraft	Inductor 1.3uH 20% 2.38mOhm 22.5A Isat 16.5A Irms
Q1	1	FDD8447L_F085	Fairchild Semiconductor	Trans MOSFET N-CH 40VDS 11mOhm@4.5V 10mOhm@6V 20nC 10nC 1.97nF 0.25nF 175°C 50A 3.8W 2.3°C/W 2.39mm 70.1mm^2 TO-252 3L (DPAK)
Q2	1	FDS6294	Fairchild Semiconductor	Trans MOSFET N-CH 30VDS 14.4mOhm@4.5V 14mOhm@6V 10nC 4.75nC 1.21nF 0.323nF 175°C 13A 3W 25°C/W 1.75mm 31mm^2 SO 8L NB
R4	1	ERJ2GEJ513X	Panasonic	Res Thick Film 0402 51K Ohm 5% 0.1W(1/10W) ±200ppm/°C Pad SMD Automotive T/R
R5	1	CRCW06032R20JNEAHP	Vishay	Res Thick Film 0603 2.2 Ohm 5% 0.25W(1/4W) ±200ppm/°C Pad SMD Automotive T/R
R9	1	ERJ3EKF5762V	Panasonic	Res Thick Film 0603 57.6K Ohm 1% 0.1W(1/10W) ±100ppm/°C Pad SMD Automotive T/R
R11	1	ERJ3EKF5900V	Panasonic	Res Thick Film 0603 590 Ohm 1% 0.1W(1/10W) ±100ppm/°C Pad SMD Automotive T/R
RF	1	ERJ3EKF2002V	Panasonic	Res Thick Film 0603 20K Ohm 1% 0.1W(1/10W) ±100ppm/°C Pad SMD Automotive T/R
RFB1	1	ERJ3EKF4642V	Panasonic	Res Thick Film 0603 46.4K Ohm 1% 0.1W(1/10W) ±100ppm/°C Pad SMD Automotive T/R
RFB2	1	ERJ3EKF1022V	Panasonic	Res Thick Film 0603 10.2K Ohm 1% 0.1W(1/10W) ±100ppm/°C Pad SMD Automotive T/R
RT	1	ERJ3EKF2742V	Panasonic	Res Thick Film 0603 27.4K Ohm 1% 0.1W(1/10W) ±100ppm/°C Pad SMD Automotive T/R

Simulation Results

Efficiency - Mon Nov 19 2018 10:34:10

EFFICIENCY

Default

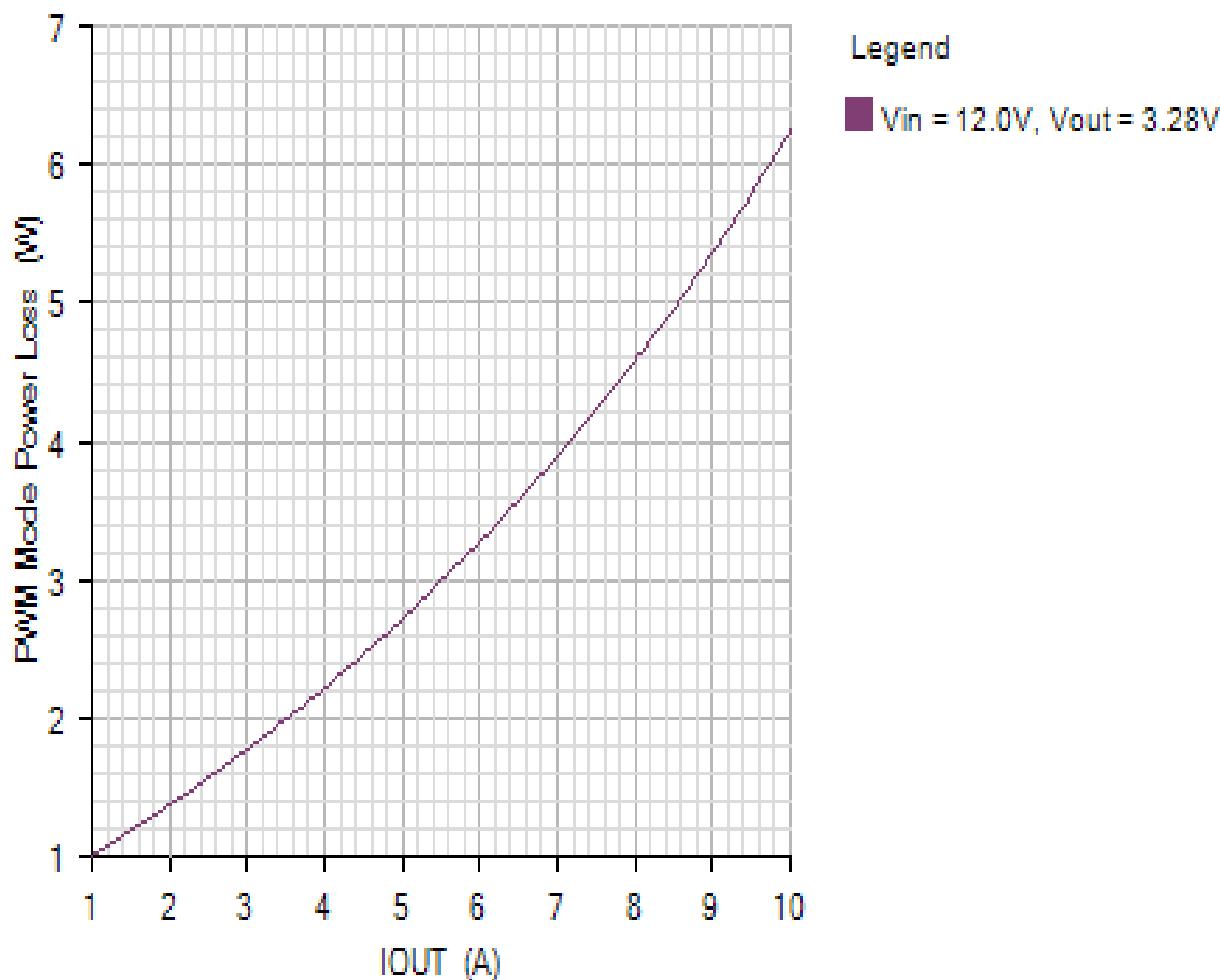
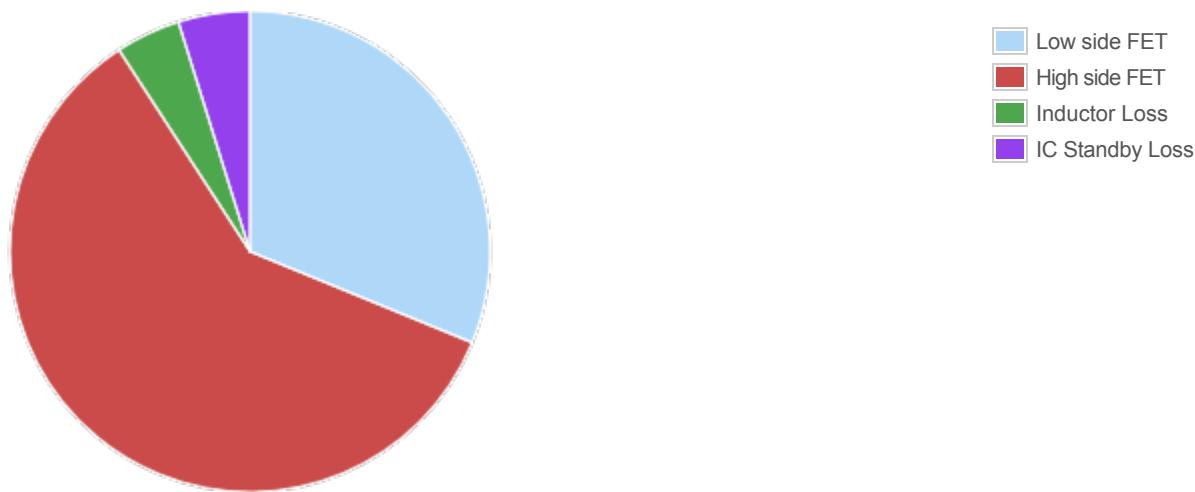


Legend

Vin = 12.0V, Vout = 3.28V

POWER LOSS

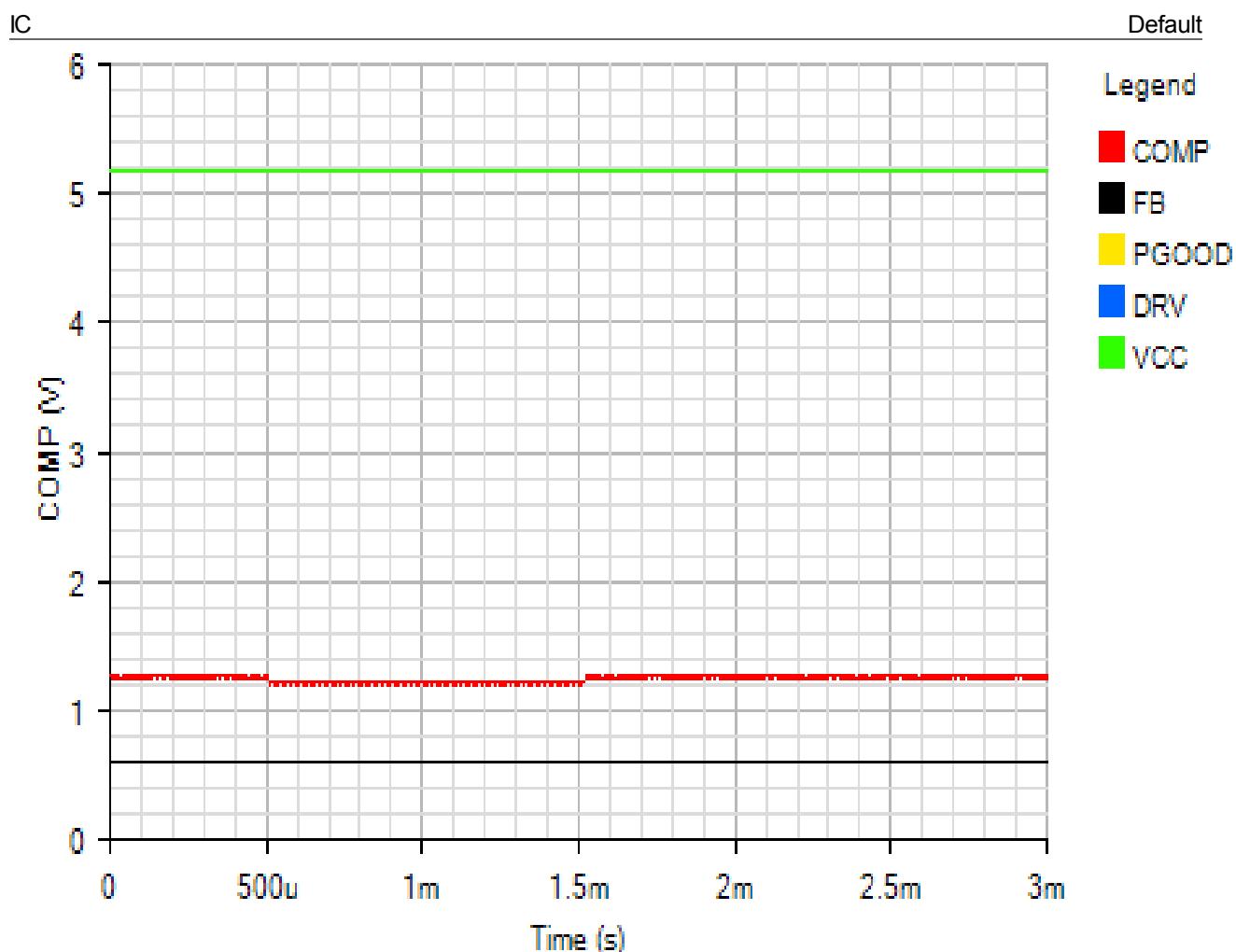
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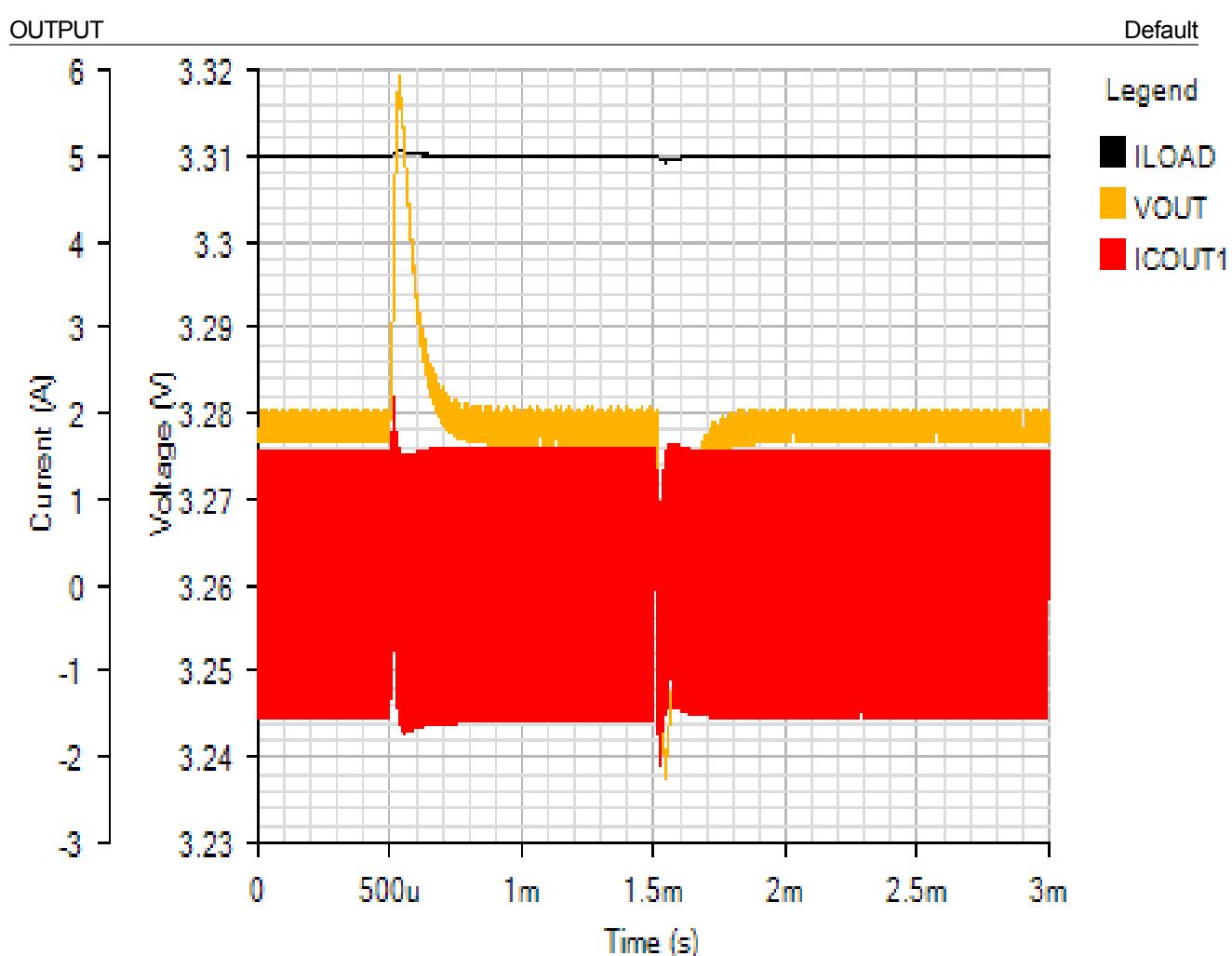
Losses

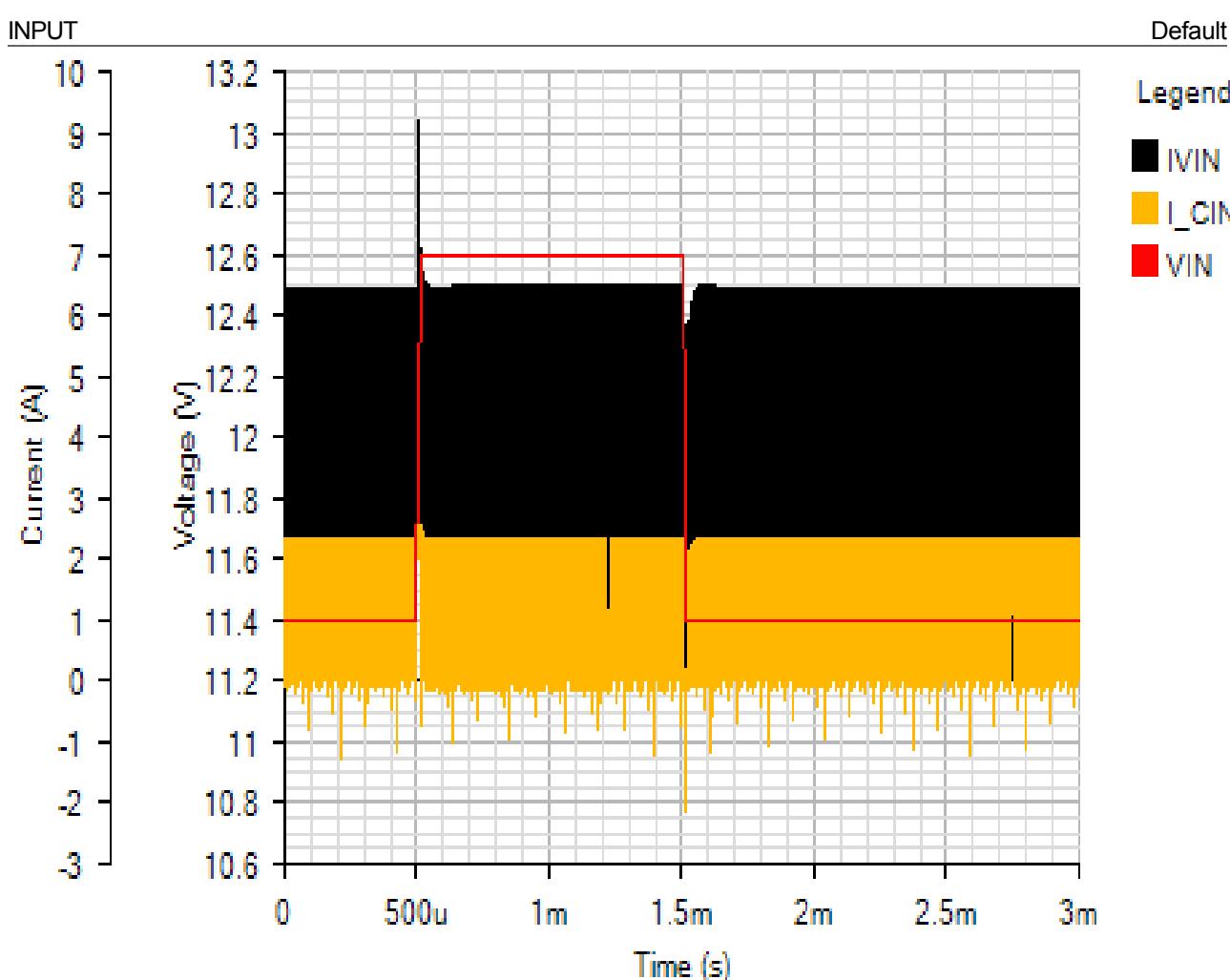


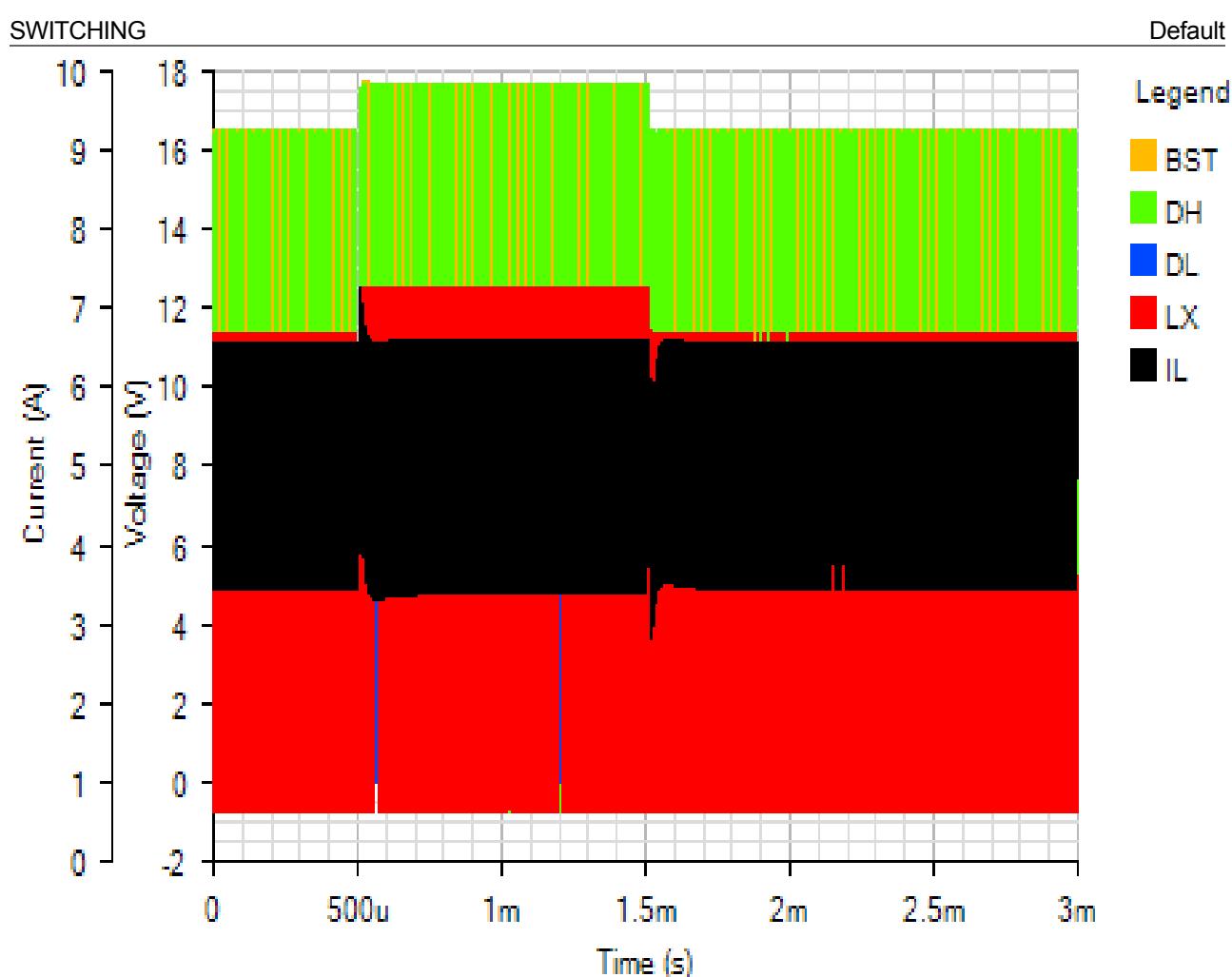
Component	Loss (W)	% of total
Low side FET	1.952136	31.2
High side FET	3.732495	59.6
Inductor Loss	0.273397	4.4
IC Standby Loss	0.3018	4.8
Total	6.259827	100

Line Transient - Mon Nov 19 2018 10:34:10

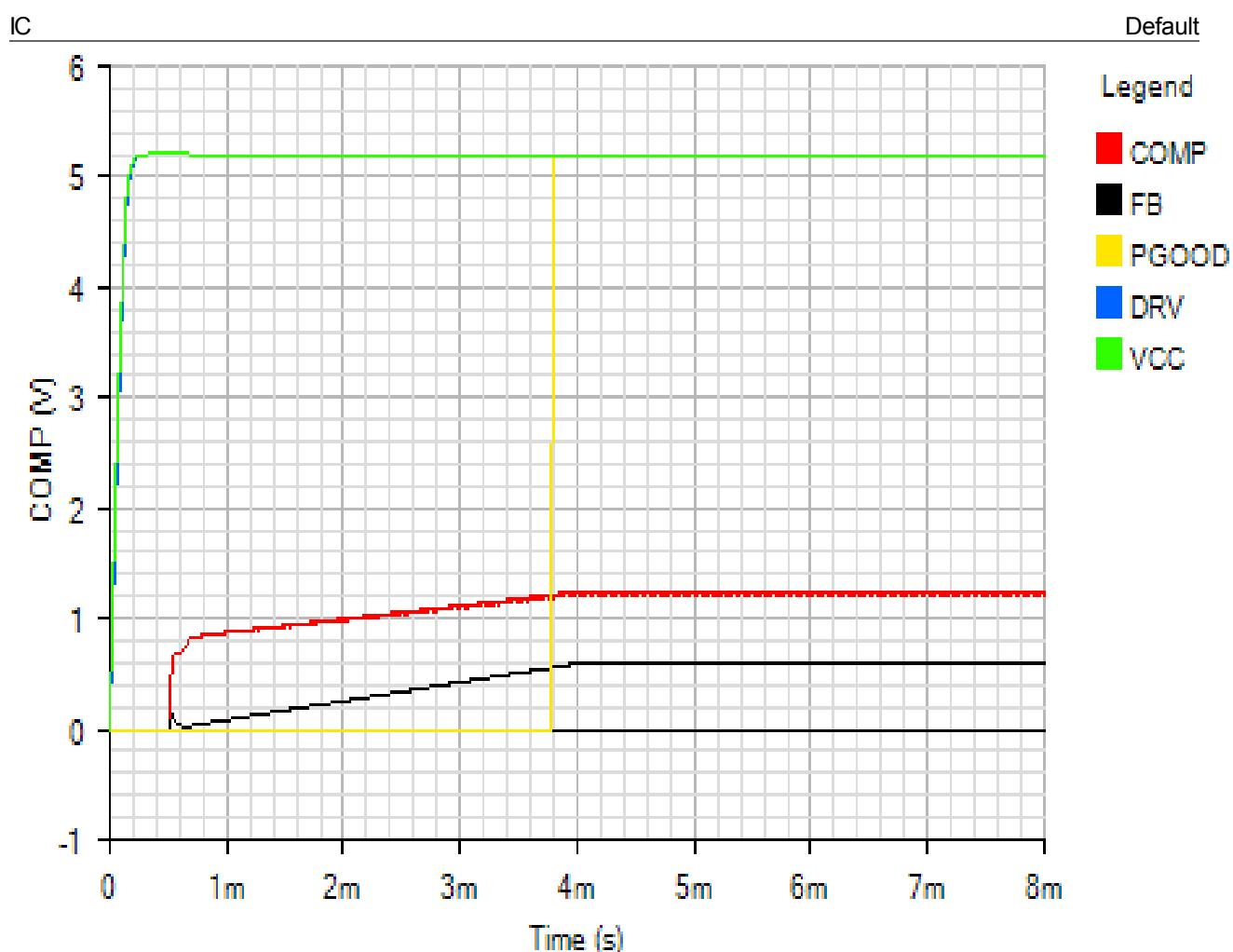






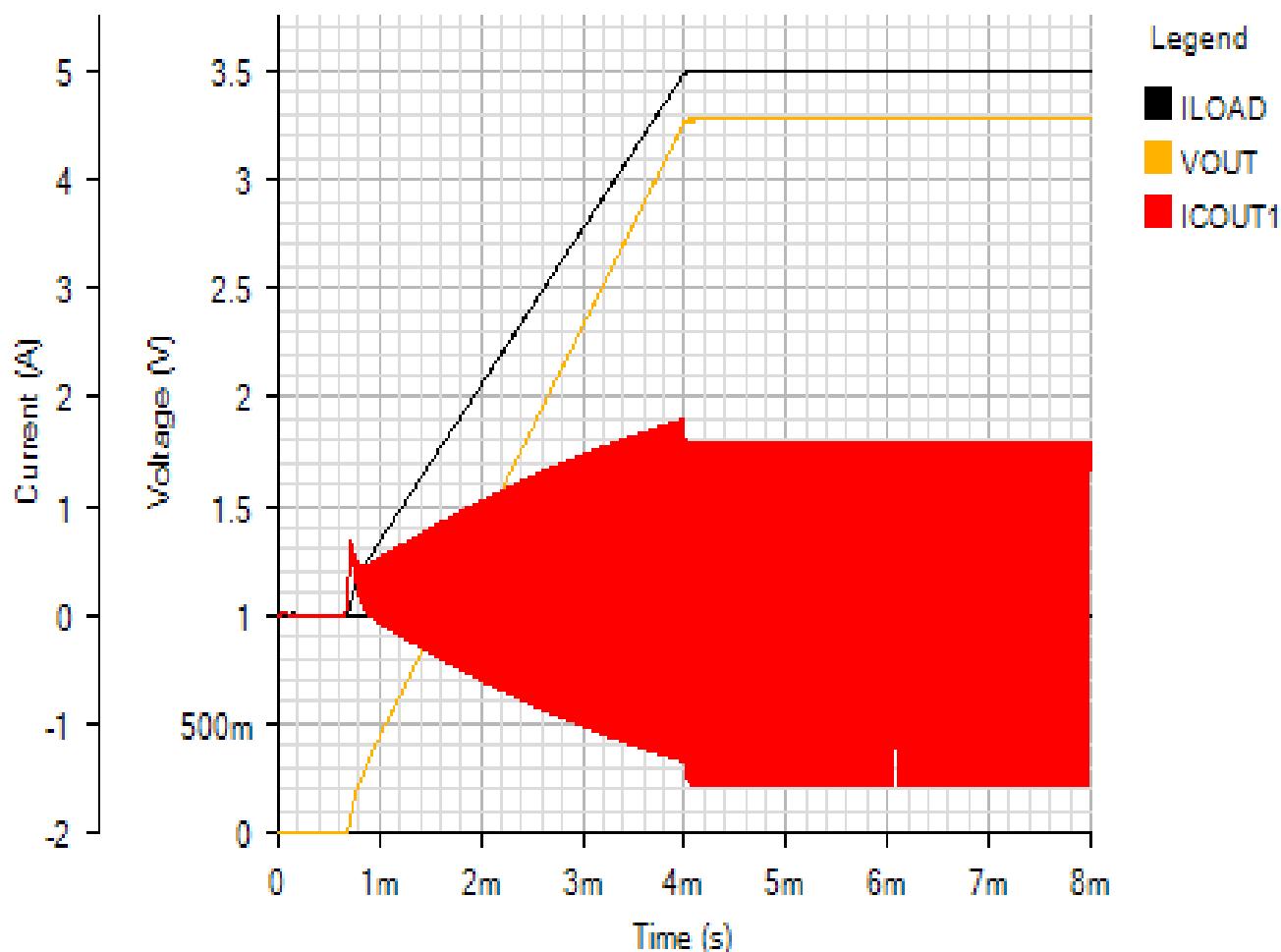


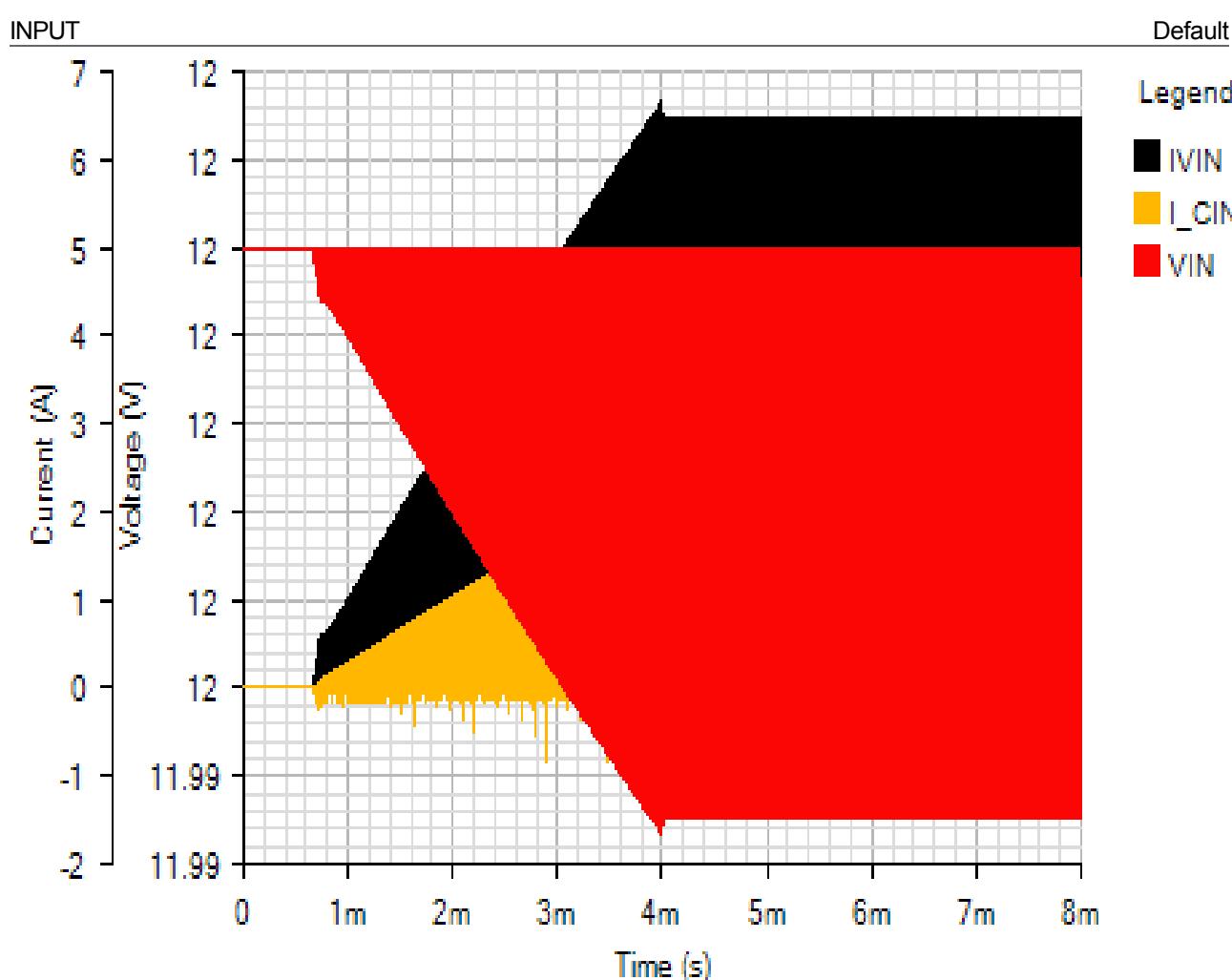
Start Up - Mon Nov 19 2018 10:34:10

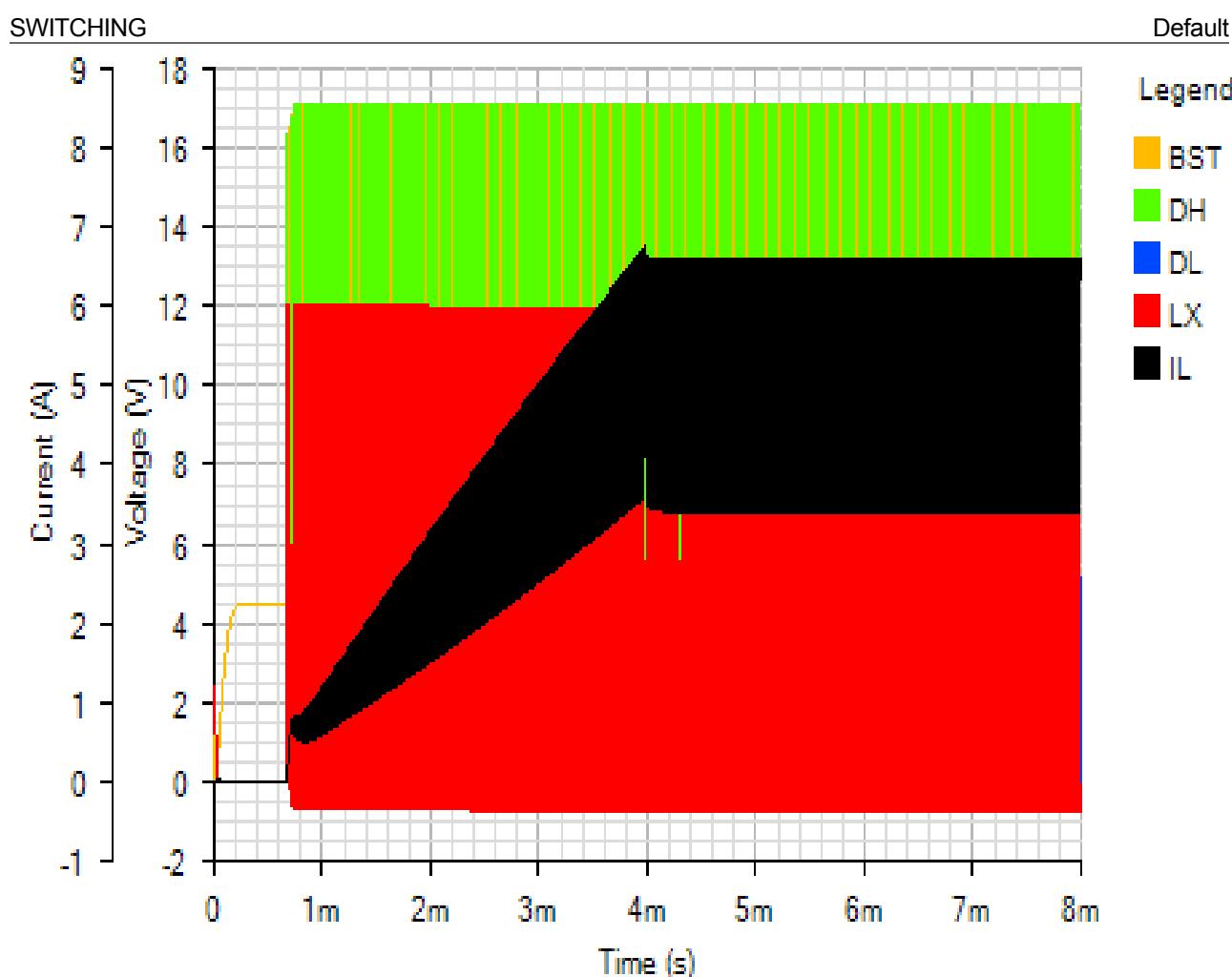


OUTPUT

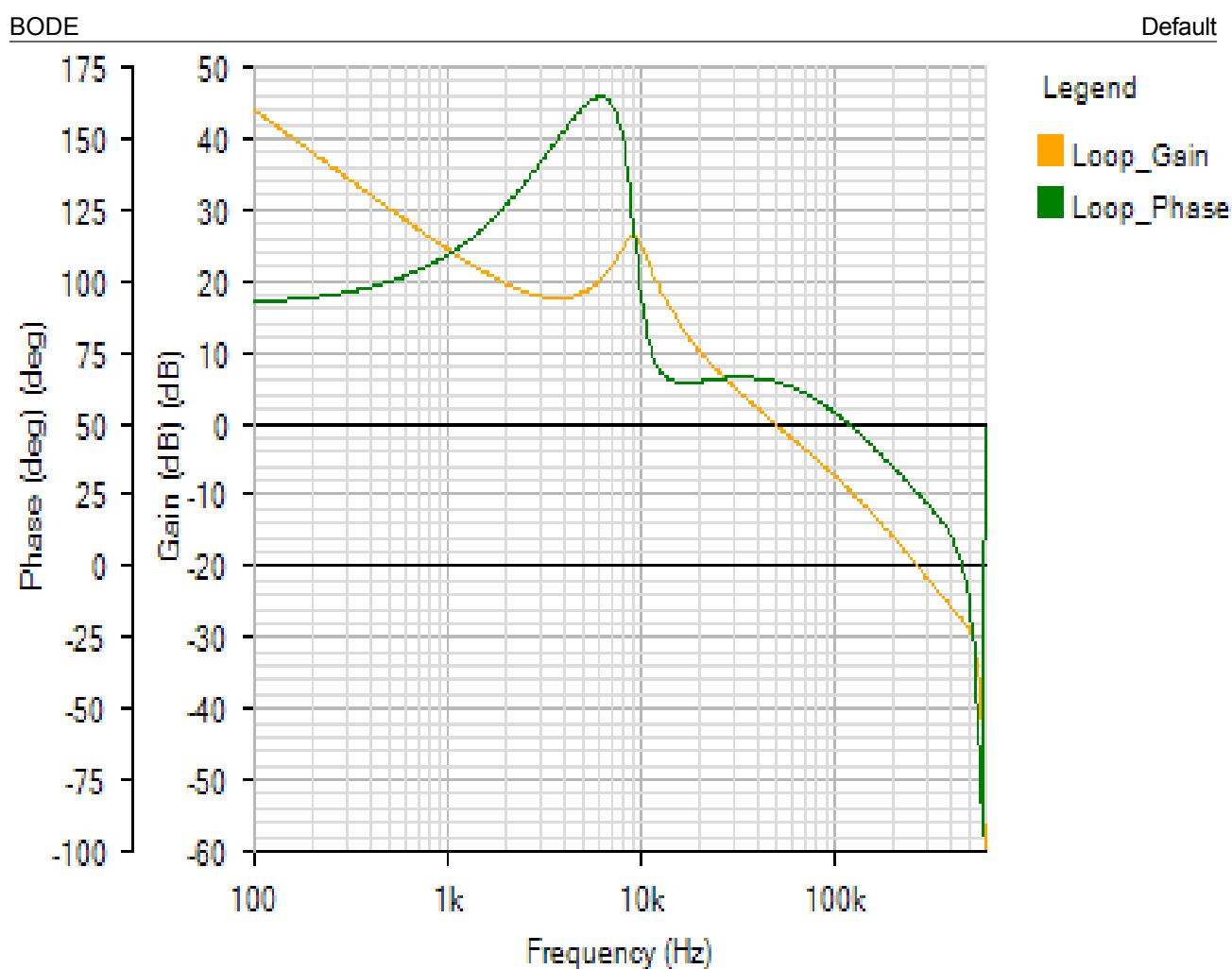
Default



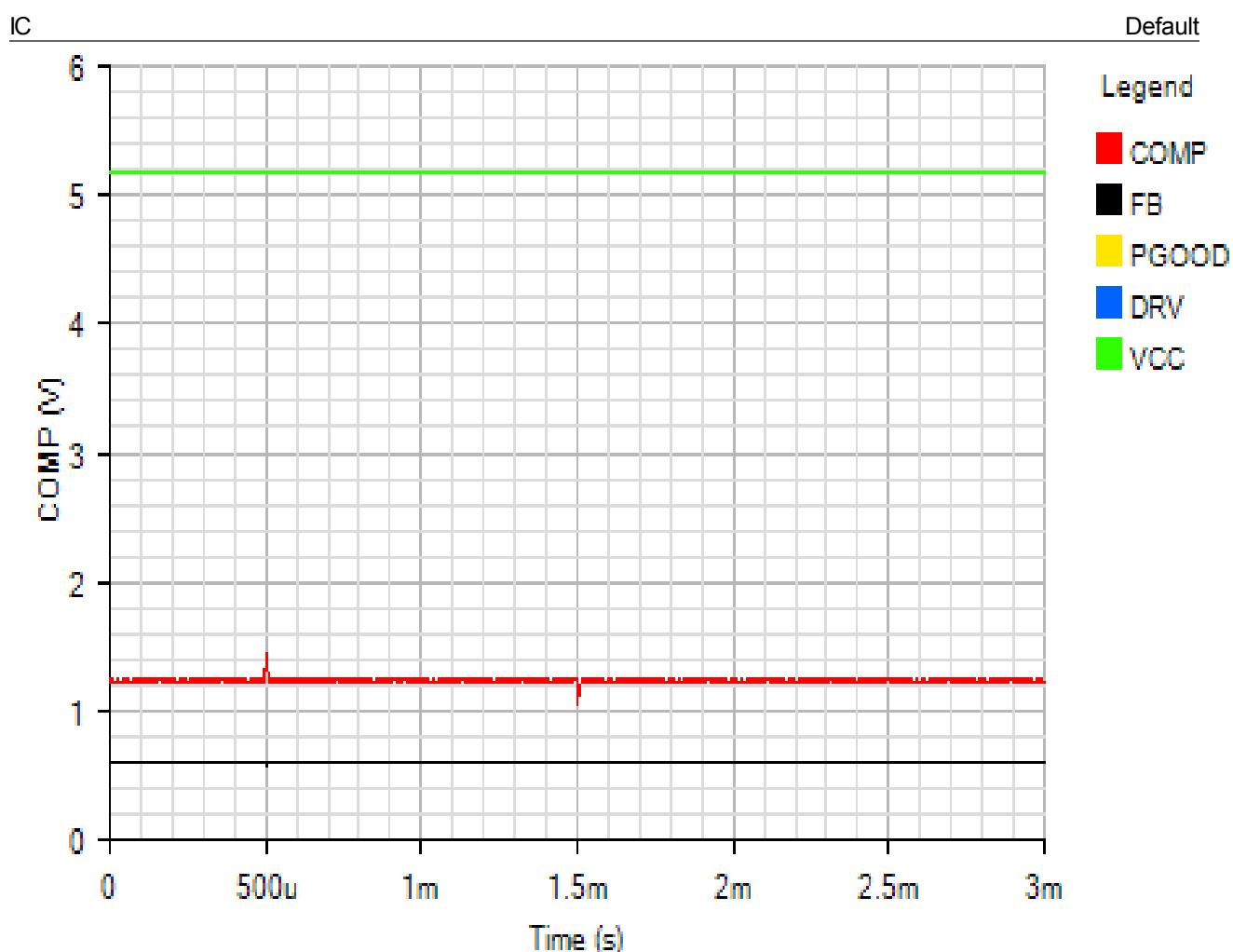


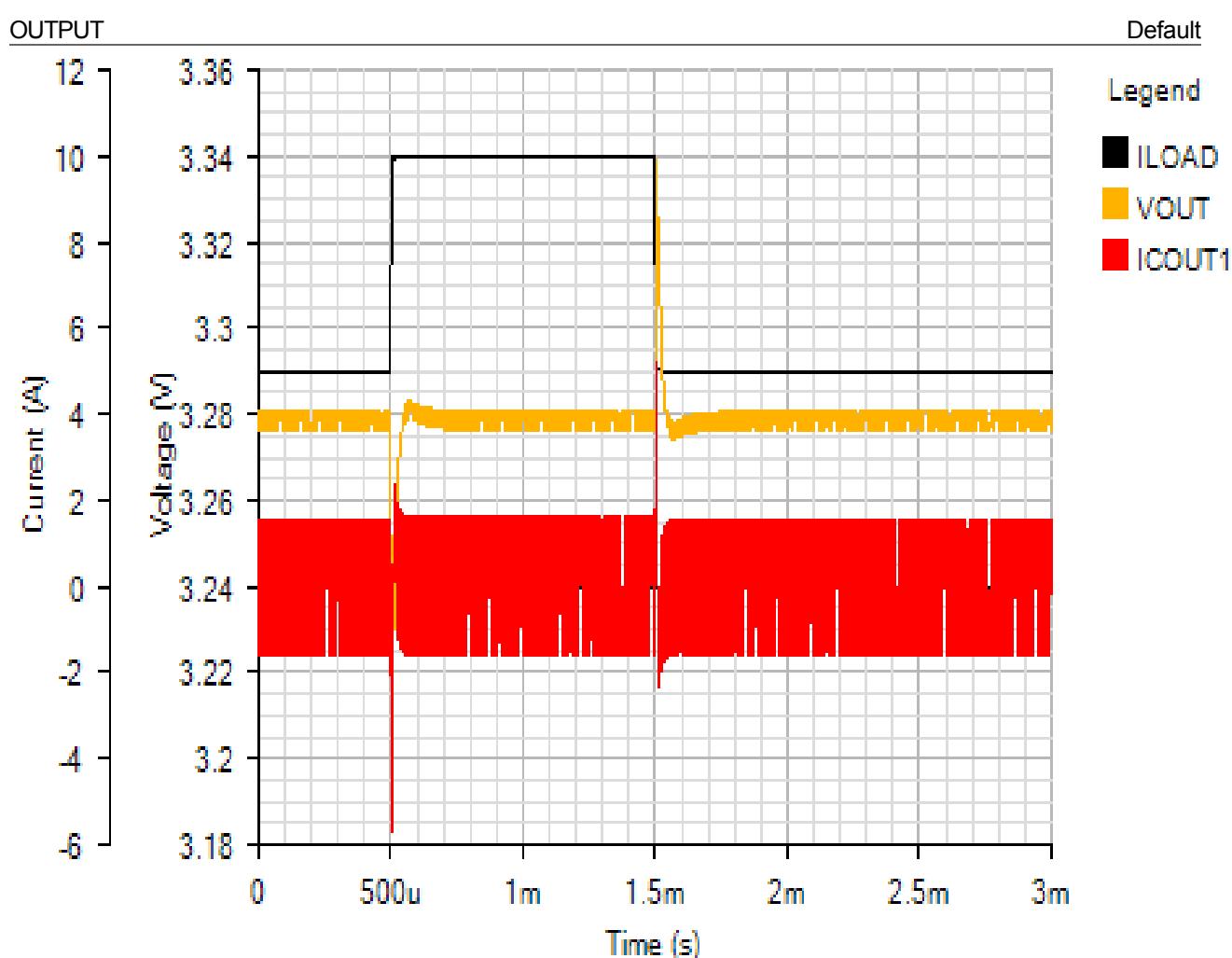


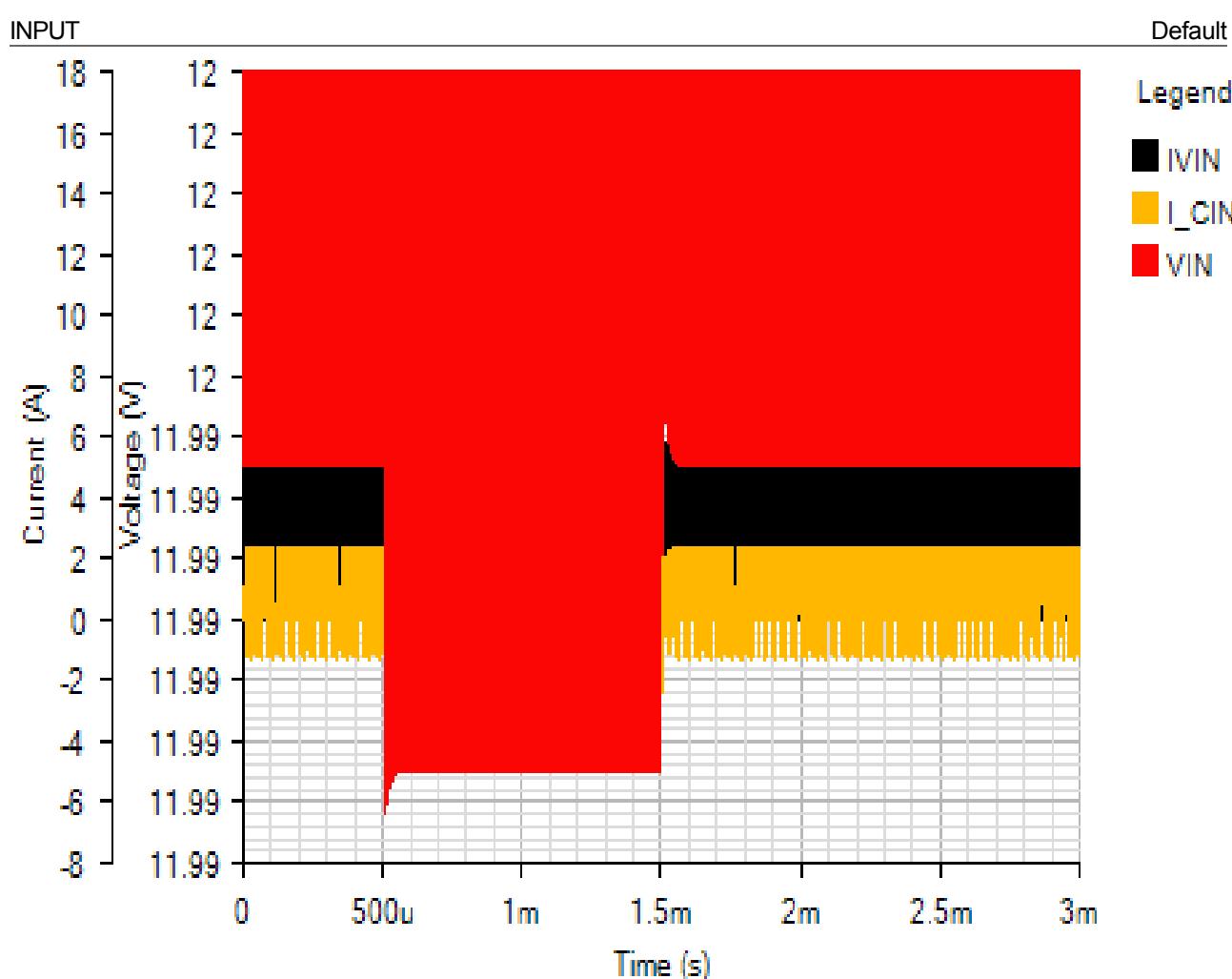
AC Loop - Mon Nov 19 2018 10:34:10

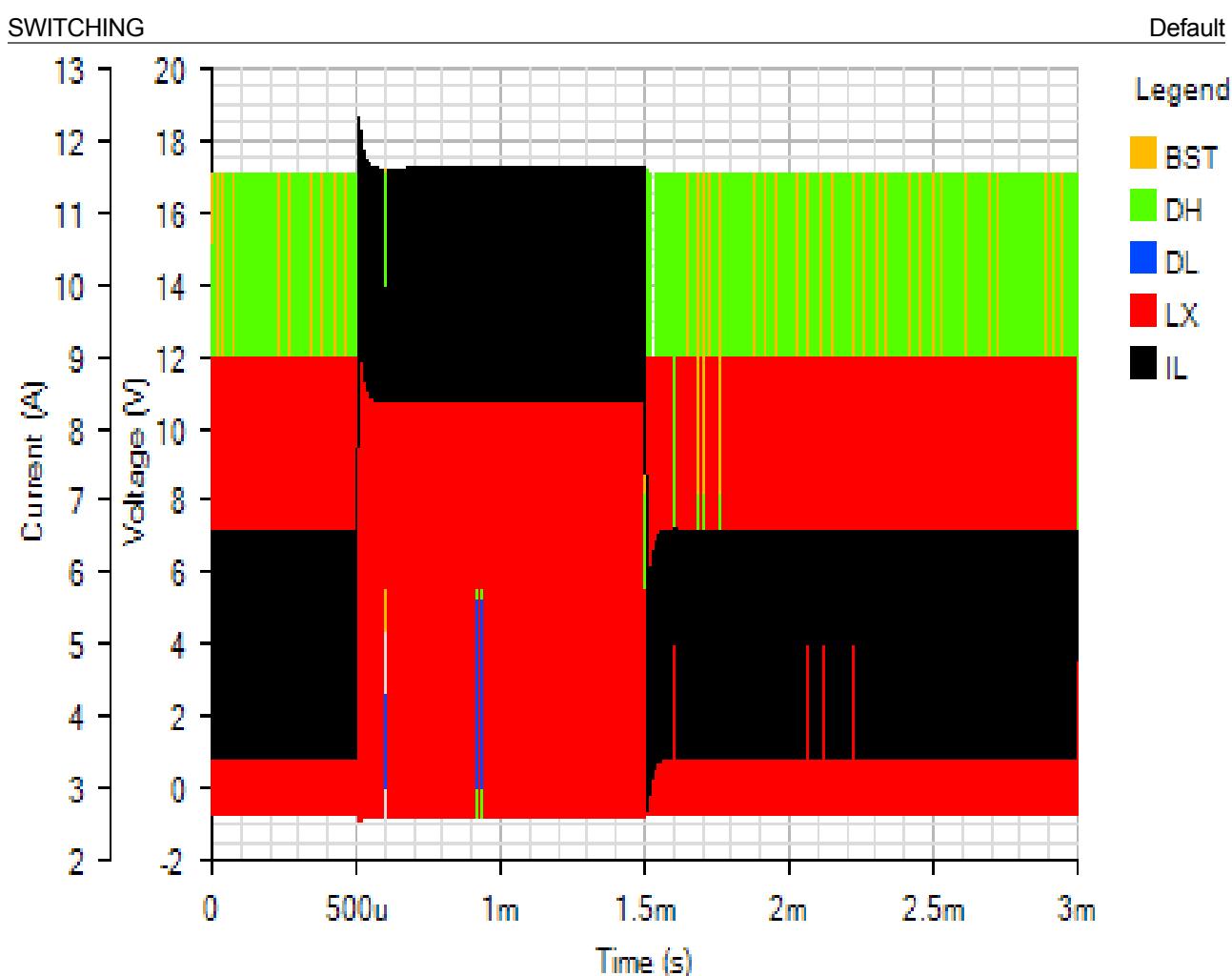


Load Step - Mon Nov 19 2018 10:34:10

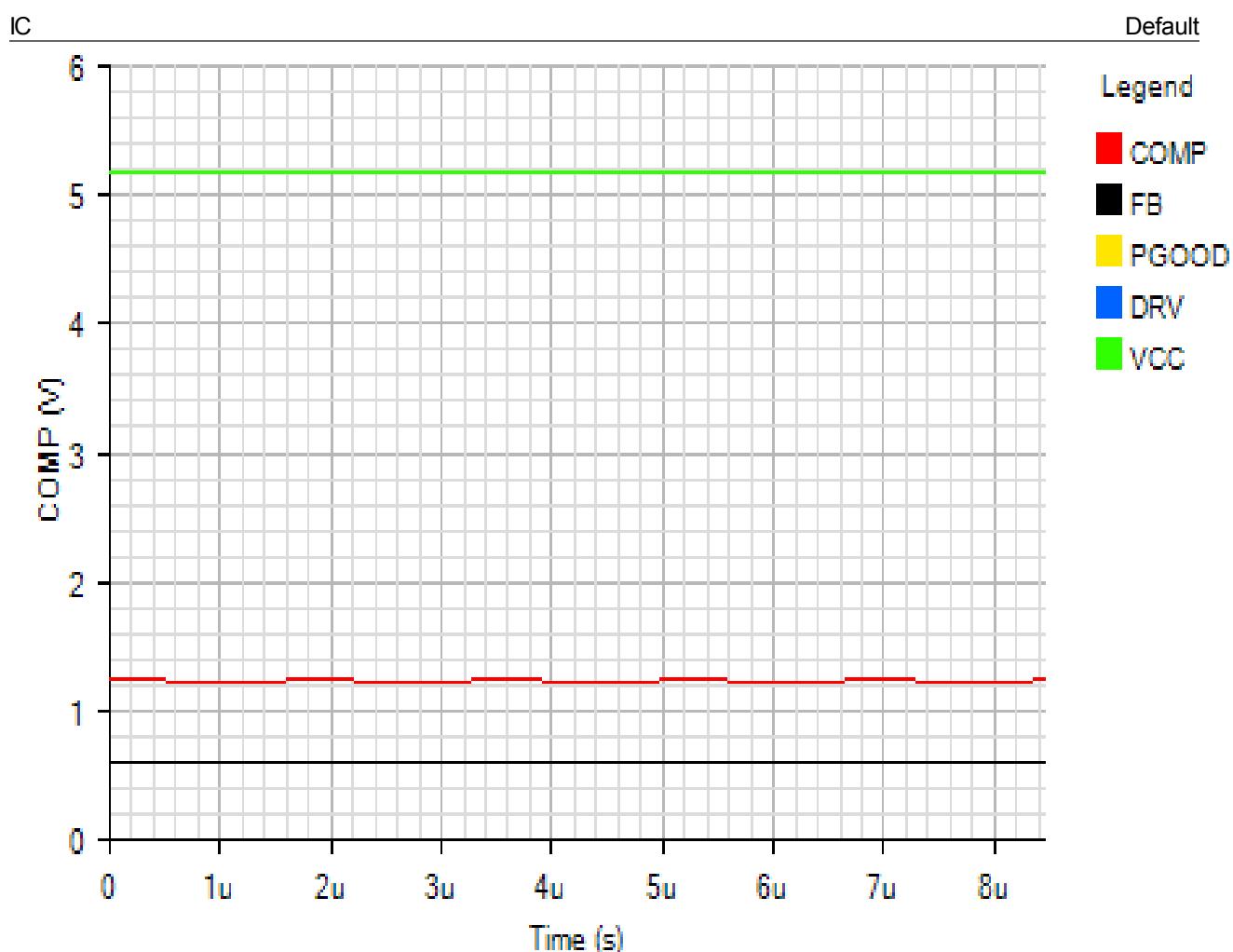


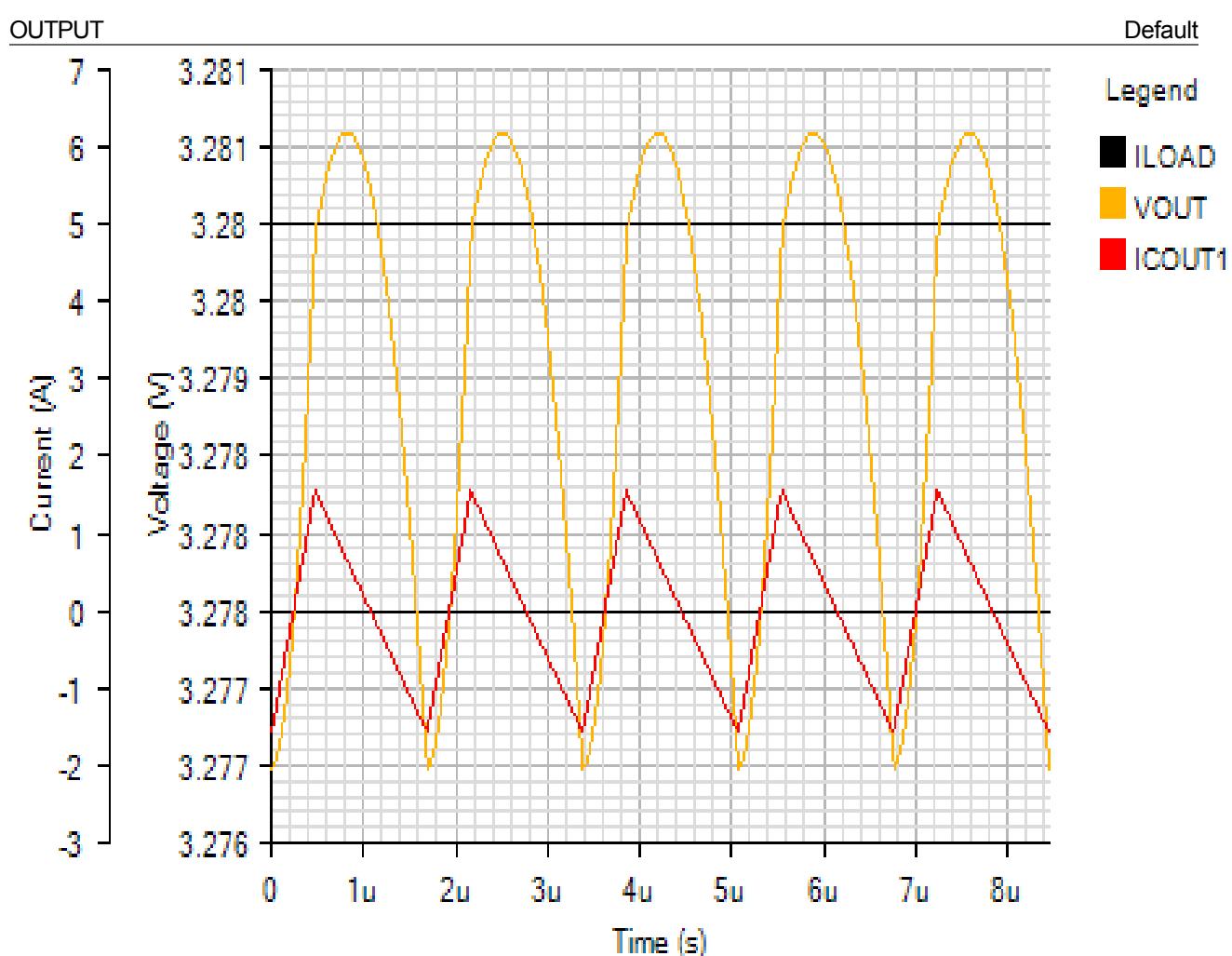


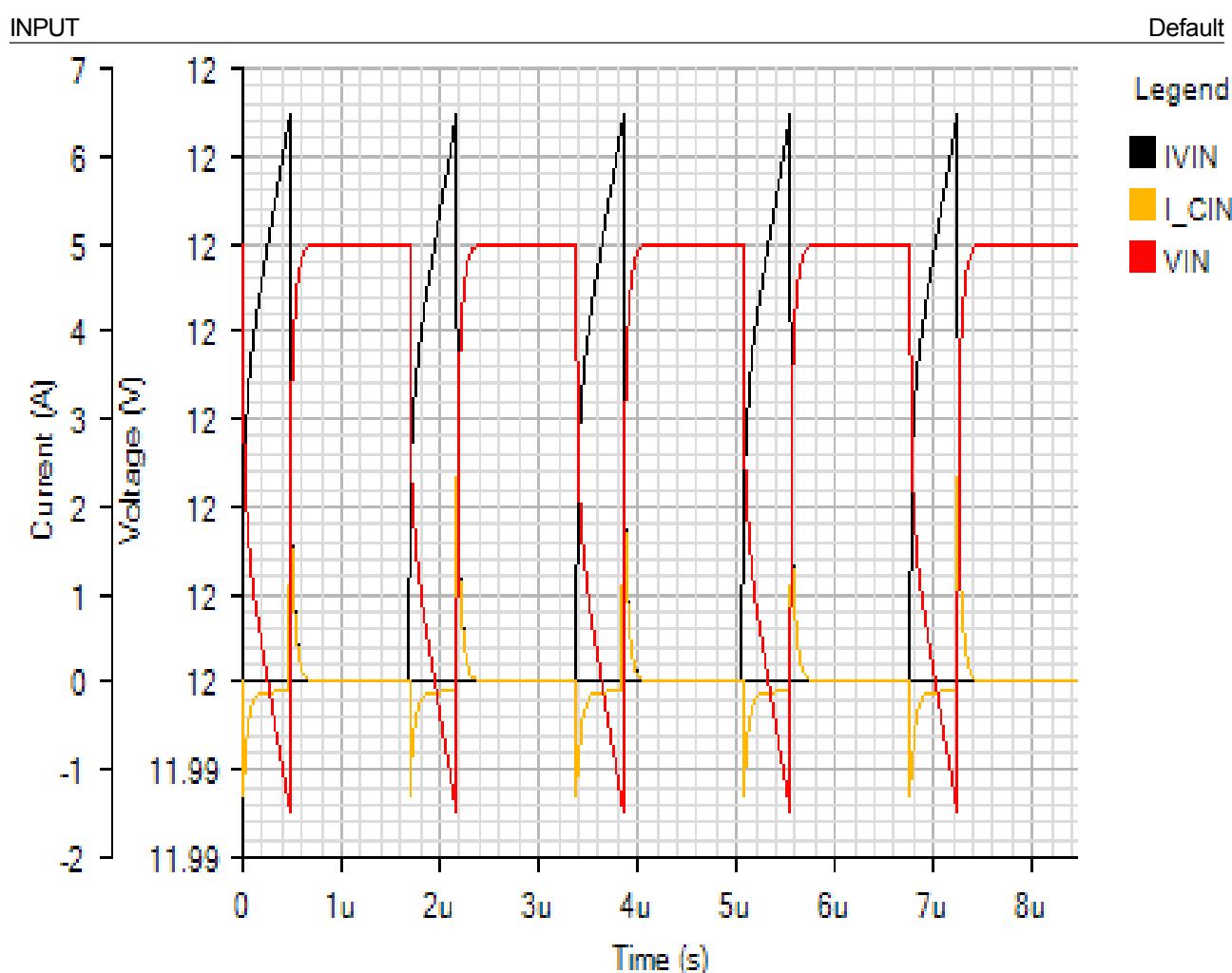




Steady State - Mon Nov 19 2018 10:34:10







SWITCHING

Default

